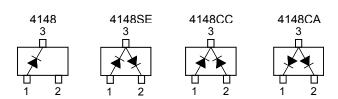
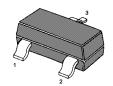
MMBD4148 / SE / CC / CA

SURFACE MOUNT SWITCHING DIODE





MMBD4148 Marking Code: 5D MMBD4148SE Marking Code: A7 Marking Code: A4 MMBD4148CC MMBD4148CA Marking Code: A1 SOT-23 Plastic Package

Absolute Maximum Ratings (T_a = 25 °C)

Parameter	Symbol	Value	Unit
Maximum Repetitive Reverse Voltage	V_{RRM}	100	V
Reverse Voltage	V_R	75	V
Average Rectified Current	I _{F(AV)}	200	mA
DC Forward Current	I _{FM}	600	mA
Recurrent Peak Forward Current	I _{FRM}	700	mA
Non-repetitive Peak Forward Surge Current at pulse width = 1 s at pulse width = 1 µs	I _{FSM}	1 2	А
Total Device Dissipation	P _{tot}	350	mW
Operating Junction Temperature	T _J	150	°C
Storage Temperature Range	T _S	- 55 to + 150	°C

Characteristics at T_a = 25 °C

Parameter	Symbol	Min.	Max.	Unit
Forward Voltage at I _F = 10 mA	V _F	-	1	V
Reverse Breakdown Voltage at I_R = 100 μ A at I_R = 5 μ A	$V_{(BR)R}$	100 75	-	V
Reverse Current at V_R = 20 V at V_R = 75 V at V_R = 20 V, T_a = 150 °C	I _R	- - -	25 5 50	nΑ μΑ μΑ
Reverse Recovery Time at I_F = 10 mA, V_R = 6 V, I_{RR} = 1 mA, R_L = 100 Ω	t _{rr}	-	4	ns
Total Capacitance at $V_R = 0 V$, $f = 1 MHz$	C _T	-	4	pF





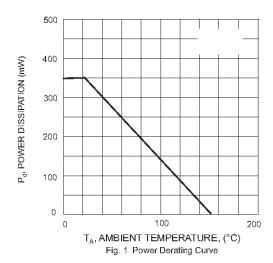
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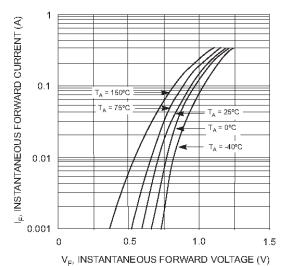




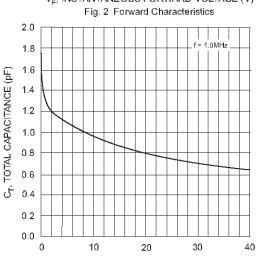


Dated: 10/10/2008





10000 IR. INSTANTANEOUS REVERSE CURRENT (nA) T. = 125°C 1000 100 T_A = 75°C <u>≡</u> T_A = 25°C 10 =-40°C 0.1 40 80 100



V_R, INSTANTANEOUS REVERSE VOLTAGE (V) Fig. 3 Typical Reverse Characteristics

 $V_{R^{\prime}}$ REVERSE VOLTAGE (V) Fig. 4 Typical Capacitance vs. Reverse Voltage



SEMTECH ELECTRONICS LTD.

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Dated: 10/10/2008